

# PATENT

TECHNOLOGY  
18  
45US  
W

Examiner: Phuc Dang

Group Art Unit: 2818

Docket No.: 1303.045US

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PATENT & TRADEMARK OFFICE

This paper is in response to the Office Action mailed on January 2, 2003. Please amend the above-identified patent application as follows.

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**IN THE TITLE**

Please amend the title throughout the USPTO records to read "ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATORS".

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